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(54) **MONOLITHIC INTEGRATION TECHNIQUES FOR FABRICATING PHOTODETECTORS WITH TRANSISTORS ON SAME SUBSTRATE**

MONOLITHISCHE INTEGRATIONSVERFAHREN ZUR HERSTELLUNG VON FOTODETEKTOREN MIT TRANSISTOREN AUF DEMSELBEN SUBSTRAT

TECHNIQUES D'INTÉGRATION MONOLITHIQUE POUR FABRIQUER DES PHOTODÉTECTEURS PRÉSENTANT DES TRANSISTORS SUR LE MÊME SUBSTRAT

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